



Модуль диодный

МДД-800-24



Средний прямой ток				I _{FAV}		800 А			
Повторяющееся импульсное обратное напряжение				U _{RRM}		800 - 2400 В			
U _{RRM} , В	800	1000	1200	1400	1600	1800	2000	2200	2400
Класс по напряжению	8	10	12	14	16	18	20	22	24
T _j , °C	– 60 ÷ 150								

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T _j (°C)	VALUE			UNIT
				Min	Type	Max	
I _{F(AV)}	Mean forward current	180° half sine wave 50Hz Single side cooled, T _C =100°C	150			800	A
I _{F(RMS)}	RMS forward current		150			1256	A
V _{RRM}	Repetitive peak reverse voltage	V _{RRM} tp=10ms V _{RsM} = V _{RRM} +100V	150	800		2400	V
I _{RRM}	Repetitive peak current	at V _{RRM}	150			45	mA
I _{FSM}	Surge forward current	10ms half sine wave V _R =0.6V _{RRM}	150			22.0	KA
I ² t	I ² T for fusing coordination					2420	A ² s*10 ³
V _{FO}	Threshold voltage		150			0.72	V
r _F	Forward slop resistance					0.18	mΩ
V _{FM}	Peak forward voltage	I _{FM} =2400A	25			1.80	V
R _{th(j-c)}	Thermal resistance Junction to case	At 180° sine Single side cooled				0.058	°C /W
R _{th(c-h)}	Thermal resistance case to heat sink	At 180° sine Single side cooled				0.020	°C /W
V _{iso}	Isolation voltage	50Hz,R.M.S,t=1min, I _{iso} :1mA(max)		2500			V
F _m	Terminal connection torque(M12)				14		N·m
	Mounting torque(M8)				12		N·m
T _{stg}	Stored temperature			-40		125	°C
W _t	Weight				3500		g
Outline	MTD7						

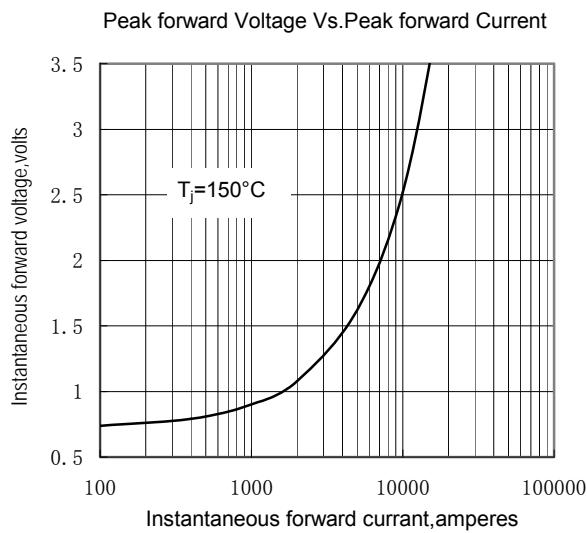


Fig.1

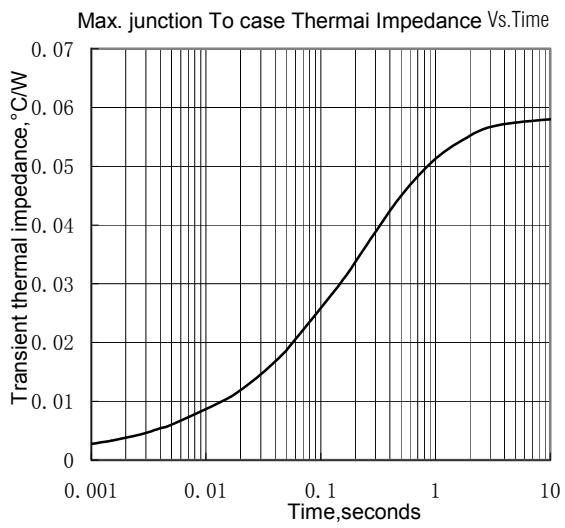


Fig.2

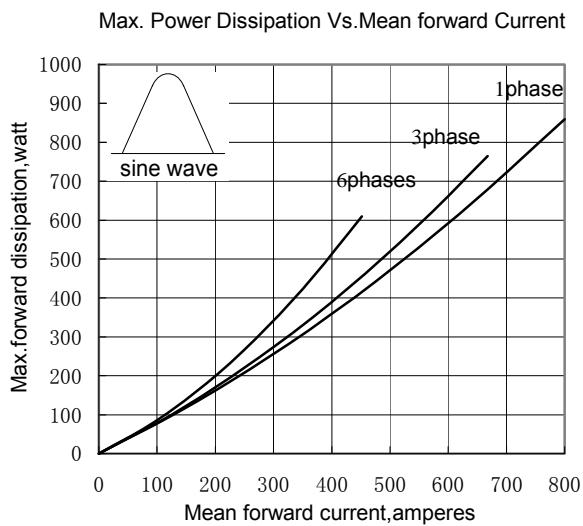


Fig.3

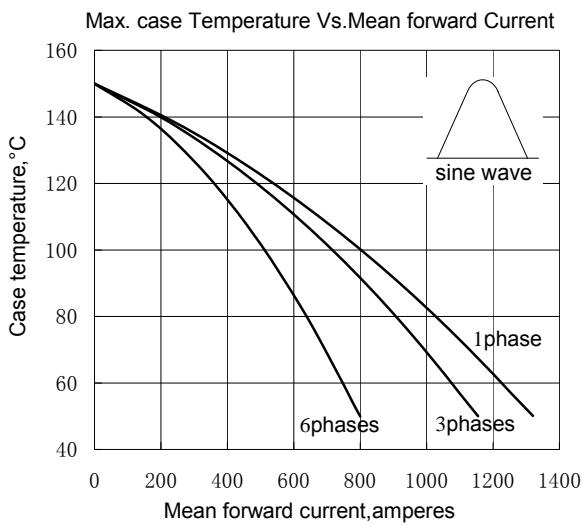


Fig.4

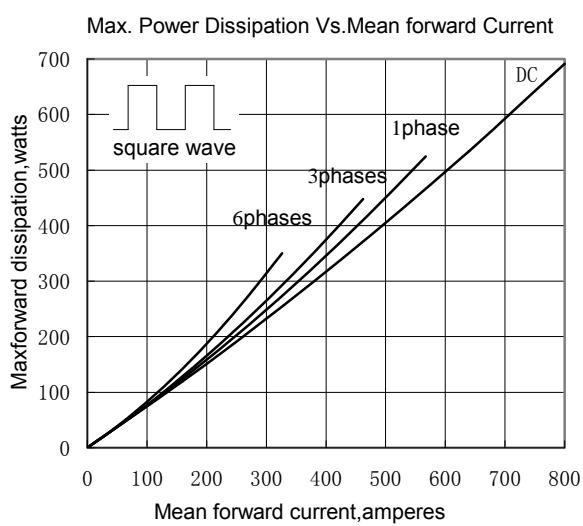


Fig.5

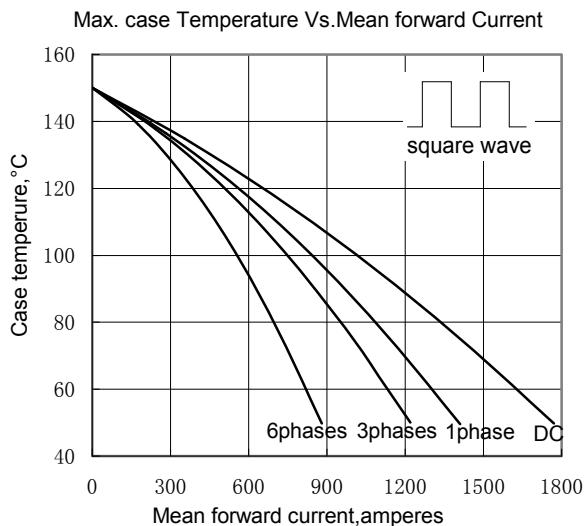


Fig.6

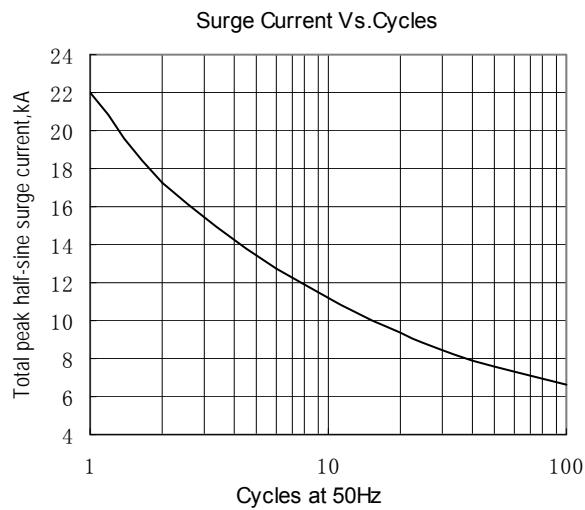


Fig.7

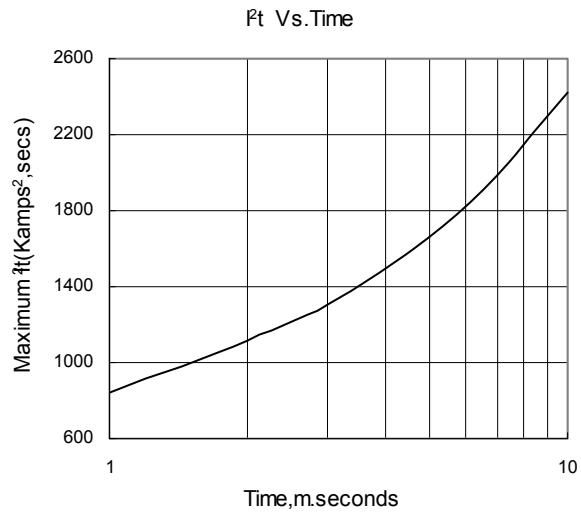
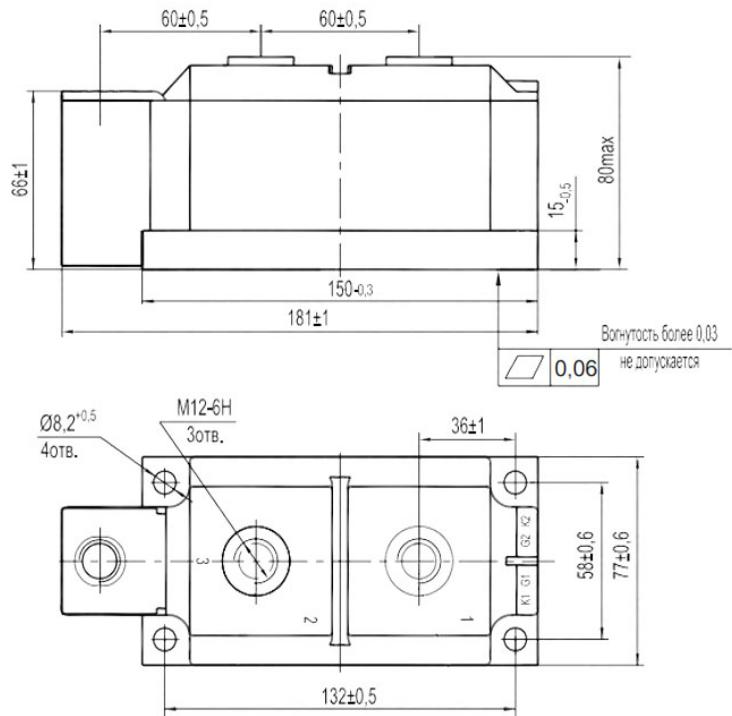


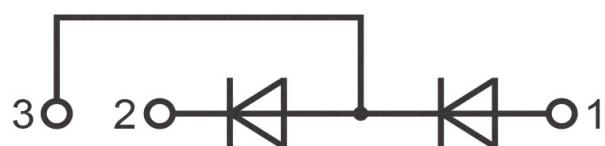
Fig.8

ГАБАРИТНЫЕ РАЗМЕРЫ

Тип корпуса: MDT7



Все размеры в миллиметрах



3 – Анод/Катод, 2 – Катод, 1 – Анод